



Transys
Electronics
LIMITED

RB461F SCHOTTKY DIODE

FEATURES

Power dissipation

P_D : 150 mW ($T_{amb}=25^\circ C$)

Collector current

I_F : 0.7 A

Reverse voltage

V_R : 20 V

Operating and storage junction temperature range

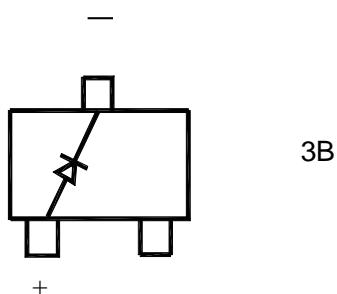
T_J, T_{stg} : -55°C to +150°C

SOT-323

1. ANODE



3. CATHODE



ELECTRICAL CHARACTERISTICS($T_{amb}=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)}$	$I_R=1mA$	20		V
Reverse voltage leakage current	I_R	$V_R=20V$		200	μA
Forward voltage	V_F	$I_F=700mA$		0.49	V